

CLAIMS

1. (Original) An apparatus, wherein the apparatus is a temperature-independent microscopic switch, comprising:

a substrate, wherein is at least configured to support the switch;

a conductive beam, wherein the conductive beam is at least configured to be suspended with one free end;

means for engaging, wherein the means for engaging at least engages the conductive beam to allow signal transmission; and

at least one tether, wherein the at least one tether is at least configured to be attached to the substrate and attached to the conductive beam.

2. (Currently Amended) The apparatus of Claim 1, wherein the apparatus further comprises means for insulation, wherein the means for insulation at least provides a non-conductive barrier between the conductive beam and at least one electrode when the ~~microscope~~ microscopic switch is engaged.

3. (Original) The apparatus of Claim 2, wherein the means for insulation further comprise air.

4. (Original) The apparatus of Claim 2, wherein the means for insulation further comprise Silicon Oxide (SiO₂).

5. (Original) The apparatus of Claim 2, wherein the means for insulation further comprise Silicon Nitride (Si_3N_4).

6. (Currently Amended) The apparatus of Claim 1, wherein the apparatus further comprises an ohmic contact at least during a portion of when the microscopic switch is engaged.

7. (Currently Amended) An apparatus, wherein the apparatus is a temperature-independent microscopic switch, comprising:

a plurality of electrodes, wherein the plurality of second electrodes are on a substrate;
a least one elastically deformable member spring means, wherein the at least one spring means elastically deformable member is at least configured to be attached to at least one of the plurality of electrodes at one end;

a conductive beam, wherein the conductive beam is at least configured to be suspended, and wherein the beam is at least configured to be attached to the at least one elastically deformable member spring means at a second end; and

means for engaging, wherein the means for engaging at least engages the conductive beam to allow signal transmission.

8. (Original) The apparatus of Claim 7, wherein the apparatus further comprises means for insulation, wherein the means for insulation at least provides a non-conductive barrier between the conductive beam and at least one electrode when the microscopic switch is engaged.

9. (Original) The apparatus of Claim 8, wherein the means for insulation further comprise air.

10. (Original) The apparatus of Claim 8, wherein the means for insulation further comprise Silicon Oxide (SiO₂).

11. (Original) The apparatus of Claim 8, wherein the means for insulation further comprise Silicon Nitride (Si₃N₄).

12. (Original) The apparatus of Claim 8, an ohmic contact when the microscopic switch is engaged.

13. (Currently Amended) The apparatus of Claim 7, wherein the at least one spring means further comprises:

a plurality of ~~spring means~~ elastically deformable members wherein each individual ~~spring means~~ elastically deformable member of the plurality of ~~spring means~~ elastically deformable members at least is configured to be attached to at least one electrode; and

each individual ~~spring means~~ elastically deformable member of the plurality of ~~spring means~~ elastically deformable members is at least configured to be connected to the conductive beam.

14. (Original) The apparatus of Claim 13, wherein the apparatus further comprises means for insulation, wherein the means for insulation at least provides a non-conductive barrier between the conductive beam and at least one electrode when the microscopic switch is engaged.

15. (Original) The apparatus of Claim 14, wherein the means for insulation further comprise being selected from a group of air, Silicon Oxide (SiO_2), and Silicon Nitride (Si_3N_4).

16. (Currently Amended) The apparatus of Claim 13, wherein the apparatus further comprises an ohmic contact at least during a portion of when the microscopic switch is engaged.

17. (Original) A method of operation of a temperature-independent microscopic switch, comprising:

engaging the switch;

signal transmission through the switch once engaged;

disengaging the switch once signal is transmitted;

preventing of warping of a flexible beam that is configured to at least operate as a throw arm once the temperature-independent microscopic switch is engaged.

18. (Original) The method of Claim 17, wherein the step of preventing of warping further comprises engaging tethers.

19. (Currently Amended) The method of Claim 17, wherein the step of preventing warping further comprises compressing a elastically deformable member spring means.

20. (Withdrawn) A microscopic switch, comprising:

at least one first electrode, wherein a first surface of the at least one first electrode is at least configured to be coupled to the substrate on, and wherein the at least one first electrode possess at least one bump on a second surface;

a dielectric material, wherein a first surface of the dielectric is at least configured to be coupled to the second surface of the at least one first electrode, and wherein a second surface of the dielectric material is at least configured to imitate the second surface of the at least one first electrode; and

a suspended beam, wherein the suspended beam is at least configured to conform to the second surface of the dielectric material when engaged.

21. (Withdrawn) The microscopic switch of Claim 20, wherein suspended beam further comprises at least having increased stress across the entire beam when engaged.

22. (Withdrawn) The microscopic switch of Claim 20, wherein the at least one bump is designed so as to increase the restoring force of the suspended beam.

23. (Withdrawn) A method for decoupling an actuation force and a restoring force for a suspended beam in a microscopic switch, comprising:

engaging the microscopic switch, wherein the suspended beam to is pulled to a lower assembly to substantially touch the lower assembly;

imitating the surface of the lower assembly by the suspended beam once engaged; and

creating internal stress in the suspended beam when imitating the surface of the lower assembly.

24. (Original) A cantilever MEMS switch comprising a tether having at least two ends, wherein a first end of the tether is at least coupled to a substrate, and wherein, a second end of the tether is at least coupled to the a cantilever arm.

25. (Original) The cantilever MEMS switch of Claim 24, wherein the substrate is at least configured to be non-conductive.

26. (Original) The cantilever MEMS switch of Claim 25, wherein the apparatus further comprises means for insulation, wherein the means for insulation at least provides a non-conductive barrier when the microscope switch is engaged.

27. (Original) The cantilever MEMS switch of Claim 26, wherein the means for insulation further comprise air.

28. (Original) The cantilever MEMS switch of Claim 26, wherein the means for insulation further comprise Silicon Oxide (SiO₂).

29. (Original) The cantilever MEMS switch of Claim 26, wherein the means for insulation further comprise Silicon Nitride (Si₃N₄).

30. (Currently Amended) The cantilever MEMS of Claim 25, wherein the cantilever MEMS further comprises an ohmic contact at least during a portion of when the cantilever MEMS is engaged.

31. (Currently Amended) A fixed-fixed MEMS switch comprising:
a plurality of electrodes;
a suspended conductive beam; and
a plurality of elastically deformable members spring means, wherein each of the elastically deformable members spring means is at least coupled to at least one electrode at a first end, and wherein each of the elastically deformable members spring means is at least coupled to the suspended conductive beam at a second end.

32. (Original) The fixed-fixed MEMS switch of Claim 31, wherein the fixed-fixed MEMS switch further comprises a substrate, wherein the substrate is at least configured to be non-conductive, and wherein the substrate is at least coupled to the plurality of electrodes.

33. (Original) The fixed-fixed MEMS switch of Claim 32, wherein the fixed-fixed MEMS switch further comprises means for insulation, wherein the means for insulation at least provides a non-conductive barrier when the fixed-fixed MEMS switch is engaged.

34. (Currently Amended) The fixed-fixed MEMS switch of Claim 33, wherein wherein the means for insulation further comprise air.

35. (Original) The fixed-fixed MEMS switch of Claim 33, wherein the means for insulation further comprise Silicon Oxide (SiO₂).

36. (Original) The fixed-fixed MEMS switch of Claim 33, wherein the means for insulation further comprise Silicon Nitride (Si₃N₄).

37. (Currently Amended) The fixed-fixed MEMS switch of Claim 33, wherein the fixed-fixed MEMS further comprises an ohmic contact at least during a portion of when the fixed-fixed MEMS is engaged.